



# **Dual P-Channel 30-V (D-S) MOSFET**

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
- 30	0.021 at V <sub>GS</sub> = - 10 V	- 8.3		
	0.031 at V <sub>GS</sub> = - 4.5 V	- 6.8		

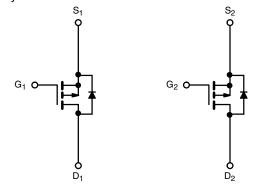
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

# RoHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

- · Load Switches
  - Notebook PCs
  - Desktop PCs
  - Game Stations
- Battery Switch





P-Channel MOSFET

# SO-8 S<sub>1</sub> 1 8 D<sub>1</sub> G<sub>1</sub> 2 7 D<sub>1</sub> S<sub>2</sub> 3 6 D<sub>2</sub> G<sub>2</sub> 4 Top View

Ordering Information: Si4923DY-T1-E3 (Lead (Pb)-free)

Si4923DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 30		V
Gate-Source Voltage		$V_{GS}$	± 20		V
Continuous Dusin Comment /T 450 000	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 8.3	- 6.2	^
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		- 6.6	- 5.0	
Pulsed Drain Current		I <sub>DM</sub>	- 30		Α
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 1.7	- 0.9	
Mariana Barra Birainatina	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.0	1.1	w
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		1.3	0.7	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana Landian La Andrian I	t ≤ 10 s	R <sub>thJA</sub>	45	62.5	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		85	110	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	26	35	

#### Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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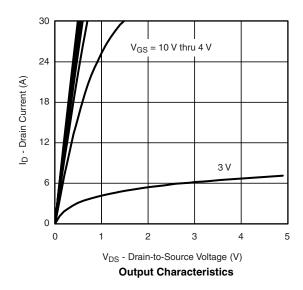
<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions Min. Typ.		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvain Cuvvant	1	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V			- 1	μΑ	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = - 30 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			- 25		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = - 5 V, V <sub>GS</sub> = - 10 V	- 30			Α	
	D	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 8.3 A		0.017	0.021	0	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 6.8 A		0.025	0.031	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 8.3 A		26		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 1.7 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$			45.5	70		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -8.3 \text{ A}$		6.5		nC	
Gate-Drain Charge	Q <sub>gd</sub>			12.6		1	
Turn-On Delay Time	t <sub>d(on)</sub>			15	25		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 15 V, $R_L$ = 15 $\Omega$		10	15		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ - 1 A, $V_{GEN}$ = - 10 V, $R_g$ = 6 $\Omega$		135	210	ns	
Fall Time	t <sub>f</sub>			80	120		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1.7 A, dI/dt = 100 A/μs		70	110		

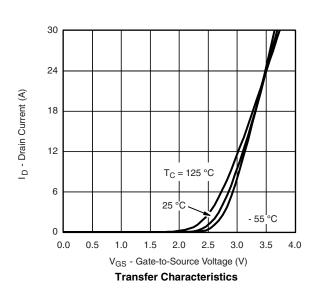
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



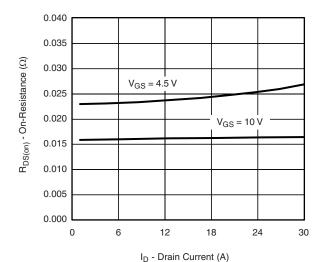




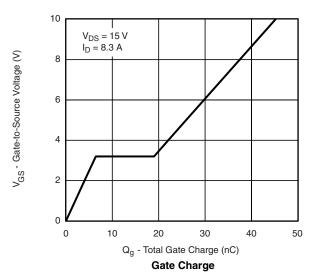


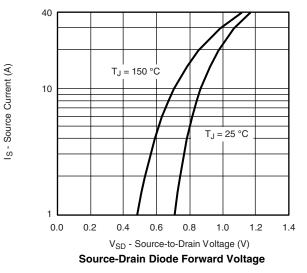


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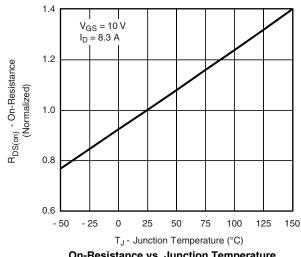
On-Resistance vs. Drain Current



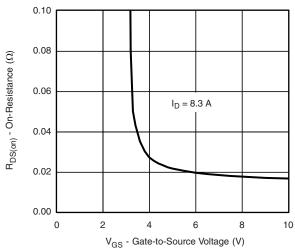


3200 2400 Ciss C - Capacitance (pF) 1600 800  $C_{\text{rss}}$ 0 10 15 25 30

V<sub>DS</sub> - Drain-to-Source Voltage (V) Capacitance



On-Resistance vs. Junction Temperature

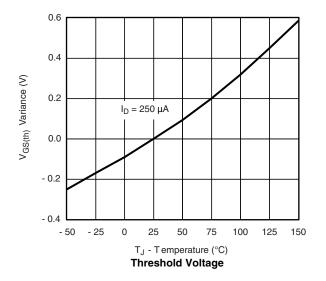


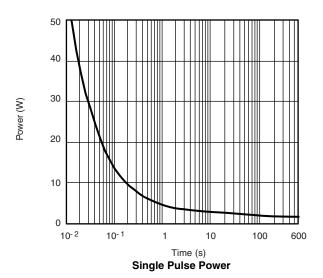
On-Resistance vs. Gate-to-Source Voltage

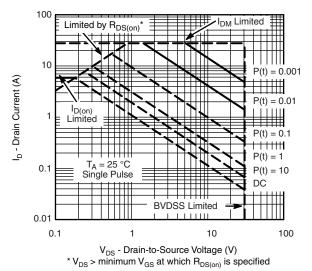
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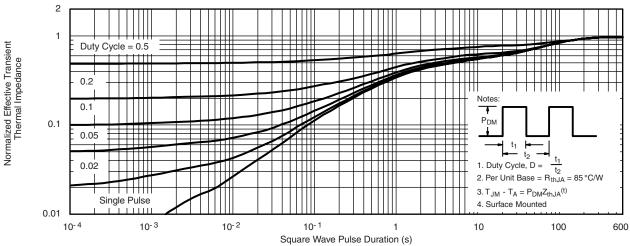
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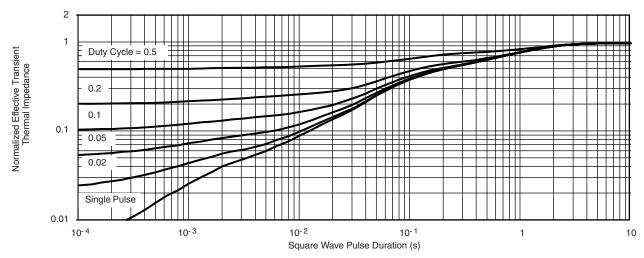
#### Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

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